

PATENT APPLICATION

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**STRUCTURE AND METHOD FOR
MANUFACTURING THIN-FILM LITHIUM
MICROBATTERIES**

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STRUCTURE AND METHOD FOR MANUFACTURING THIN-FILM LITHIUM MICROBATTERIES

Origin of the Invention

The invention described herein was made in the performance of work under a NASA contract, and is subject to the provisions of Public Law 96-517 (35 USC 202) in which the contractor has elected not to retain title.

BACKGROUND OF THE INVENTION

Field of the Invention

5 The present invention relates to thin-film batteries compatible with integrated circuit manufacturing and in particular to the method for making the same.

Description of Related Art

10 There is an ever-expanding field where solid-state thin-film batteries may be used, including critical space exploration systems. Examples include battery-backed CMOS memory, MEMS switches, and micro sensors. In
15 many of these applications, the ability to integrate a thin film battery directly onto a silicon integrated

circuit chip next to the device to be powered would reduce overall device mass and volume as well as open up the possibility of distributing power at the chip level. The ability to deposit high capacity films onto flexible polymer substrates is also appealing.

The ideal thin-film battery has a capacity approaching theoretical levels for the materials system selected, minimal capacity loss over thousands of cycles, and materials and process steps that are compatible with common silicon-based fabrication methods.

In the recent past, RF magnetron sputtered LiCoO_2 thin films have emerged as a leading candidate for use as the cathode layer in thin film solid state batteries. Films that exhibit a (104) or (101) out-of-plane texture, have grains that are > 100 nanometers in diameter, and display little to no lattice strain and are most efficient at lithium intercalation and electronic conduction. It has been shown elsewhere that an annealing step of typically 700°C induces the desired film qualities. Because this heating step is too high for many desirable substrates, such as flexible polymer materials or silicon wafers with integrated CMOS devices, an effort has been undertaken to examine the possibility of creating LiCoO_2 films with the desired material qualities without using a high temperature process step. To reach this goal, it is critical to understand the deposition parameters that affect film crystallography and composition of LiCoO_2 when sputtered at room temperature.

A range of compositions have been observed in sputtered LiCoO_2 . The Li/Co ratio has been reported to be 0.88 [9] or 1.0 ± 0.1 when sputtered using a sputter gas consisting of 100% Argon. If sputter gases comprise $\text{Ar}:\text{O}_2$ mixes of 1:10 and 1:1, the Li/Co ratio was found to be 0.8 ± 0.08 and 1.15 ± 0.02 , respectively. Concurrently, O/Co ratios ranging from 2.7 to 2.2 have been reported as well. In all cases, these films were found to be amorphous (per x-ray diffraction analysis) if deposited at room temperature and subsequently developed primarily a (003), (101), or (104) out-of-plane texture upon annealing at temperatures in excess of 600°C , depending on thickness.

In contrast to these results, preliminary experiments show that it is possible to deposit nanocrystalline LiCoO_2 films at room temperature. Some of these films have strong (104) out-of-plane textures and are found to have promising electrochemical properties.

SUMMARY OF THE INVENTION

The highest capacity thin film cathode layers (LiCoO_2) typically require an annealing step of 700°C . Since this high temperature is not compatible with silicon device technology or flexible polymer substrates, the development of a low process temperature ($<300^\circ\text{C}$) cathode layer is needed. LiCoO_2 thin-films were RF sputter deposited and subsequently incorporated into thin film batteries. A variety of deposition and post-deposition parameters were varied in an effort to

optimize film microstructure and content. Film composition and microstructure were examined using a variety of techniques including x-ray diffraction using synchrotron radiation. It was found that
5 LiCoO₂ could be deposited at room temperature in a nano-crystalline state with a strong (104) out of plane texture and a high degree of lattice distortion. By heating these layers to 300°C, the grain size is significantly increased while lattice
10 distortion is eliminated. Cycling data reveals that the heating step increases cell capacity to near theoretical values (at lower discharge currents) while significantly improving both the rate capability and discharge voltage.

15
Accordingly, it is an object of the present invention to provide a thin film battery that has near-theoretical capacities and good discharge capabilities
20 without exceeding temperatures of approximately 300°C and are compatible with silicon processing techniques, which was heretofore a major problem.

Another object of the present invention is to
25 provide a method for growing films with nano-crystalline grains oriented in the proper crystallographic direction at room temperature.

Yet another object of the present invention is
30 to provide a simplified method for manufacturing thin-film batteries by heating the films to 300°C in order to

create cathode layers that have near state of the art performance.

These and other objects, which will become
5 apparent as the invention is described in detail below,
are provided by a process for making thin-film batteries
including the steps of cleaning glass or a silicon
substrate having an amorphous oxide layer several microns
thick; defining with a mask the layer shape when
10 depositing cobalt as an adhesion layer and platinum as a
current collector; using the same mask as the preceding
step to sputter deposit LiCoO_2 in an argon-oxide gas on
the structure while rocking it back and forth; heating
the substrate to 300°C for 30 minutes; sputtering with a
15 new mask that defines the necessary electrolyte area;
evaporating lithium metal anodes using an appropriate
shadow mask; and, packaging the cell in a dry-room
environment by applying a continuous bead of epoxy around
the active cell areas and resting any thin protective
20 (i.e., insulating) over the top thereof.

Still other objects, features and advantages of
the present invention will become readily apparent to
those skilled in the art from the following detailed
25 description, wherein it is shown and described only the
preferred embodiment of the invention, simply by way of
illustration of the best mode contemplated of carrying
out the invention. As will be realized, the invention is
capable of other and different embodiments, and its
30 several details are capable of modifications in various
obvious respects, all without departing from the
invention. Accordingly, the drawings and description are

to be regarded as illustrative in nature, and not as restrictive, and what is intended to be protected by Letters Patent is set forth in the appended claims. The present invention will become apparent when taken in
5 conjunction with the following description and attached drawings, wherein like characters indicate like parts, and which drawings form a part of this application.

BRIEF DESCRIPTION OF THE DRAWINGS

10 The general purpose of this invention, as well as a preferred mode of use, its objects and advantages will best be understood by reference to the following detailed description of an illustrative embodiment with
15 reference to the accompanying drawings in which like reference numerals designate like parts throughout the figures thereof, and wherein:

20 Figure 1A is a plan view of the beginning steps of the method of the present invention.

Figure 1B is a cross-sectional view of the structure shown in Figure 1A.

Figure 2A is a plan view of an intermediate step of the method of the present invention.

25 Figure 2B is a cross-sectional view of the structure shown in Figure 2A.

Figure 3A is a plan view of an intermediate step of the method of the present invention.

30 Figure 3B is a cross-sectional view of the structure shown in Figure 3A.

Figure 4A is a plan view of the penultimate step of the method of the present invention.

Figure 4B is cross-sectional view of the structure shown in Figure 4A.

Figure 5 is a plan view of the resulting structure following steps of the present invention.

5 Figures 6A and 6B illustrate the results from the synchrotron x-ray diffraction studies of the structure in accordance with the present invention.

Figure 7 illustrates normalized (104) X-scan texture data of the structure of the present invention.

10 Figure 8 illustrates the TEM images of 80 nm thick LiCoO_2 films sputtered onto holey carbon grids in accordance with the present invention.

15 Figure 9 shows the electrochemical performance of thin film batteries comprising as-deposited 200 nm thick LiCoO_2 cathodes.

Figure 10A shows a plot of cell potential vs. capacity for a LiCoO_2 thin film battery with a 0.190 μm thick cathode.

20 Figure 10B contains a plot showing the cycle life of a typical heat-treated LiCoO_2 cell.

DETAILED DESCRIPTION

OF THE PREFERRED EMBODIMENTS

25 The following description is provided to enable any person skilled in the art to make and use the invention and sets forth the best modes contemplated by the inventors of carrying out their invention. Various modifications, however, will remain readily apparent to those skilled in
30 the art, since the general principles of the present invention have been defined herein specifically to provide

low process temperature nano-crystalline LiCoO_2 thin-film cathodes.

Referring now to the drawings and Figure 1A in particular, a plan view of a beginning step of the process of the present invention is shown. This part of the process is for creating a large area thin-film cathode layer of LiCoO_2 that has favorable crystallographic texturing and grain size for use in a thin-film solid state battery system. The process begins with a clean glass substrate 10 having an amorphous oxide layer 11 several microns thick. With the use of a shadow mask (not shown) the beginning elements 12 and 13 of the battery are formed by depositing 100 nm of cobalt as an adhesion layer 14 and 300 nm of platinum as a current collector layer 15. Deposition conditions are 10 mTorr of argon, at 300W of rf power, with a substrate to target distance of 70 mm. The substrate is kept stationary during growth of layers 14 and 15. The cross-sectional view of Figure 1B shows the same structural elements with the same reference numerals.

Referring now to Figure 2A, a plan view of an intermediate step of the method of the present invention is shown. The same shadow mask (not shown) used in forming the structure shown in Figure 1A and 1B is used in this step as well. Hence, the plan view of Figure 2A is the same as the plan view of Figure 1A. However, as can be seen in Figure 2B, an additional layer 16 of LiCoO_2 is deposited to form the cathode. The sputter gas is a 3:1 $\text{Ar}:\text{O}_2$ mix with a total pressure of 10mTorr. The substrate to target distance is 70 mm. However, a key difference is depositing this layer 16 is that the substrate is rocked

back and forth underneath the target at an amplitude of 5 cm. This motion serves to create an ovalar area (approximately 3 x 5 cm²) on the substrate within which the desired (104) out of plane texture is found. The shadow mask for the cathode layers must be situated within this area to insure proper layer performance. The film thickness can range from 5 to 5000 nm (at least), where the thicker the film corresponds to batteries with a higher capacity.

The substrate is removed from the vacuum sputter chamber (not shown) and is kept in a controlled dry (, 1% humidity) environment. X-ray diffraction is performed on these layers to insure that the cathode layer contains nano-crystalline LiCoO₂ grains oriented with their (104) planes parallel to the plane of the substrate. The substrate is then placed in an oven and heated to 300°C and held at this temperature for 0.5 hours. The oven is located in the dry environment to insure that moisture contact with the cathode layer is minimized. The resulting film layers should have a fully relaxed LiCoO₂ hexagonal crystal structure, have some grains that approach 30 nm in diameter, and have a strong (104) out of plane texture.

Referring now to Figure 3A, a plan view of the deposition of the LiPON solid electrolyte layer 18 is shown. The substrate and newly added layers is placed back into the sputter chamber with a new shadow mask (not shown) that defines the electrolyte area, thereby forming the layer 18. It is important that the sputter chamber be very clean before starting this step. The substrate to target distance is 90 mm this time, and the substrate holder is a

massive metallic object that is kept in thermal contact with the substrate, which helps to cool the substrate during deposition. This precautionary step helps to overcome any non-uniform heating problems. Approximately 1
5 micron of LiPON is then deposited onto the cathode layer 16 of elements 12 and 13. The LiPON is sputtered from a pressed and sintered LiPO_4 3" sputter target in pure N_2 environment. A target power of 100 watts is used. The substrate is again rocked back and forth during growth of
10 the layer 18 as well.

It has been discovered empirically that the rocking action eliminates localized heating and averages the film composition and thickness over the important areas
15 deposited, thereby greatly reducing lateral variations in the deposited LiPON layer 18. The electrolyte or LiPON layer 18 is grown to a thickness of 1 to 1.5 μm . The electrolyte lithium phosphorus oxynitride (LiPON) is a recently discovered material that has good lithium ion
20 conductivity and, more importantly, is stable in contact with metallic lithium at high voltages.

Referring now to Figure 4A, a plan view of the resulting structure is shown after lithium metal anodes
25 are evaporated using an appropriate shadow mask (not shown). In particular, the structure is removed from the deposition chamber, while still warm, and transferred to an evaporation chamber. Using the anode shadow mask, less than 2 microns of lithium are evaporated onto the layer 18,
30 thereby forming the anode layer 20. Figure 4B shows this same structure in cross-section.

Following the above, the structure is sealed in a dry environment by placing a glass cover over it and attaching with epoxy. More specifically, the structure is placed in a dry environment (< 1% humidity) to cool after the preceding step of forming the anode layer 20. The active anode/electrolyte area is surrounded with a bead of 5 minute epoxy 21. Care is to be taken here to assure that the leads from the anode and current collector are not full enclosed by the epoxy bead. Next, a thin insulating protective layer 22 (such as glass) is placed over the active area such that a hermetic seal is created using the epoxy. The assembly is then allowed to dry. As can be seen in the plan view of Figure 5, an anode 23 and a cathode 24 are exposed for connection to external circuitry. The result is the thin film battery in accordance with the present invention, which is shown in Figure 5.

The final step is to connect the battery to a circuit. In order to do this, part of the LiCO_2 layer 16 is removed in order to form a good ohmic contact. The part removed is that part exposed outside of the packaging, which is removed by using HCl acid soaked into a wiper. The exposed part is then cleaned with methanol. After this, a bead of solder is melted onto the exposed part of the platinum layer 15 and an electrical lead is welded to the layer 15 by means of the solder.

The highest capacity thin-film cathode layers (LiCoO_2) typically require an annealing step of 700°C . Since this high temperature is not compatible with silicon device technology or flexible polymer substrates, the

development of a low process temperature (e.g., < 300°C) cathode layer is required. LiCoO₂ thin-films are RF-sputter deposited and subsequently incorporated into thin film batteries. A variety of deposition and post-deposition parameters are varied in an effort to optimize film microstructure and content. Film composition and microstructure are examined using a variety of techniques including x-ray diffraction using synchrotron radiation. It was found that LiCoO₂ could be deposited at room temperature in a nano-crystalline state with a strong (104) out of plane texture and a high degree of lattice distortion. By heating these layers to 300°C, the grain size is significantly increased while lattice distortion is eliminated. Cycling data reveals that the heating step increases cell capacity to near theoretical values (at lower discharge currents) while significantly improving both the rate capability and discharge voltage.

The highest capacity per unit volume for a thin film battery, > 65 μAh/cm²μm, has been reported from cells fabricated using a LiCoO₂ cathode layer in conjunction with a LiPON electrolyte and lithium anode (theoretical capacity approximately 69μAh/cm²μm). These cells displayed excellent cycle life (over 10,000 cycles), discharge rate capability (mA range), and discharge voltages (> 3.9 V). However, it was also reported that a 700°C anneal of the cathode layer was required; the use of this high temperature precludes the use of many substrates and is not compatible with silicon device processing techniques. Nano-crystalline LiMn₂O₄ cathode can be prepared at temperatures less than 300°C, but they

display diminished capacities and cannot be effectively discharged at currents greater than $50 \mu\text{Ah}/\text{cm}^2$.

In an attempt to create the highest possible capacity thin-film battery systems, LiCoO_2 is selected as a cathode material. Though there have been numerous reports that LiCoO_2 forms a completely amorphous film when RF sputter deposited at room temperature, preliminary work indicates that the desirable polycrystalline or nano-crystalline microstructures could be created at room temperature.

Three-inch lithium cobalt oxide (LiCoO_2) sputter targets are prepared by cold pressing and sintering standard powders. The sintering temperature is set to $800\text{-}900^\circ\text{C}$ for 1 hour, and target thicknesses are 4-6 mm. The targets are subsequently bonded to aluminum backing plates using molten indium or silver epoxy.

The growth chamber is a custom-designed turbo-pumped 3-position RF planar magnetron sputter system configured in the "sputter down" geometry. A rotating substrate platen allows for the growth of multiple films on different substrates, with substrate to target distance of 7 cm. The maximum base pressure before deposition is 3×10^{-6} Torr, though most films are grown at base pressures lower than 1×10^{-6} Torr. Typically, the LiCoO_2 targets are pre-sputtered for 30 minutes before opening the shutter. The cathode films are sputtered in $\text{Ar}:\text{O}_2$ ratios ranging from 3:1 to 1:1 with a total gas flow rate of 55 sccm and pressure of 10 mTorr. Nominal target power is set to 100 W, giving a power density of 2.2

W/cm². To eliminate lateral compositional variations in the film, the substrate platen was programmed to oscillate underneath the sputter target through a range of 12° at a frequency of 0.3 Hz, a motion that swept the substrate back and forth. This motion produces an area of approximately 4x5 cm on the substrate with uniform color, thickness, and composition. LiCoO₂ deposition rate varies linearly depending on the ratio of argon to O₂ in the sputter gas; films deposited in 100% argon had a deposition rate of 210+/-5 nm/hr, while a 1:1 mix of argon and O₂ resulted in a growth rate of 175+/-10 nm/hr.

The cathode films are deposited onto cleaved test-grade silicon wafers (with native amorphous oxide intact), and C tape for compositional and structural analysis, while glass with molybdenum or platinum current collectors are used as a substrate for cell creation. Thicknesses are determined using an Alpha-Step 100 profilometer. Test cell cathode areas are defined using aluminum masks that define an area of 1.4 cm². After growth, the films are transferred to a dry room (<1% humidity air) where they are subjected to a heating step of 300°C for 1 hour. Complete thin film batteries are then fabricated using these cathodes and using a sputtered LiPON electrolyte layer and an evaporated Lithium anode. The Lithium anode is evaporated in a Denton thermal evaporator situated inside the dry room. Cathode layer composition may be determined using a combination of Rutherford back scattering (RBS) and inductively coupled plasma mass spectroscopy (ICP-MS).

Film crystalline structure is examined using x-ray diffraction conducted at the Stanford Synchrotron Radiation Laboratory (SSRL). The use of a synchrotron x-ray source is justified because these thin (typically
5 <0.4 μm), low atomic weight films yield poor counting statistics using laboratory-based x-ray systems, particularly when using the θ - 2θ geometry. A silicon (111) monochromator is used to select the wavelength of the x-ray beam, 0.124 nm (10 keV), in focused mode. To
10 quantitatively examine texture, the out of plane substrate tilt, χ was scanned while θ and 2θ were set to satisfy a particular Bragg condition. This type of scan is essentially a cross section of a pole and will be referred herein as a texture plot. The films are kept
15 under a constant helium environment during data collection to avoid moisture contamination.

To examine microstructure and grain size, plan-view transmission electron microscopy may be performed on
20 films that are deposited onto holey carbon grids. All samples are kept in an air-tight, dry environment until immediately before insertion into the TEM.

The electrochemical characteristics of the
25 batteries are examined by cycling them using an Arbin BT-2042 battery testing instrument, while cyclic voltammetry measurements are performed using a PAR 273 potentiostat. Typically, the cells are charged to 4.25 V using a maximum current of 50 μA , and discharged to 2.5 V at
30 currents ranging from 2 μA to 1 mA. During the charging cycle, the cells are held at 4.25 V while the charging current decreased to less than 2 μA .

Compositional analysis

RBS and ICP-MS analysis show that LiCoO_2 film composition depends upon the growth history of the target and composition of the sputter gas. The films grown for the studies described herein are from targets with 5-30 hours of sputtering and have Li/Co ratios of 1.1 ± 0.1 with a O/Co ratio of 2.2 ± 0.1 . These results are consistent with values cited in the literature and indicate that it is likely that a small amount of Li_2O is formed during sputtering.

X-ray diffraction

Results from the synchrotron x-ray diffraction studies are shown in Figures 6A and 6B, wherein Figure 6A illustrates a diffraction pattern collected from a LiCoO_2 powder standard; that is, collected at SSRL, powder x-ray diffraction pattern of LiCoO_2 , $\lambda = 1.24 \text{ \AA}$. Fig. 6B illustrates diffraction from 150 nm thick LiCoO_2 RF sputter films, before and after the 300°C heating step.

Using a beam energy of 10 keV ($\lambda = 1.24 \text{ \AA}$), 5 peaks can be observed in the 2θ range of 10° to 40° , including the (003), (101), and (104), which are the 3 strongest reflections reported in the literature for sputtered hexagonal LiCoO_2 films. Fig. 6B contains diffraction patterns collected from a 150 nm thick LiCoO_2 film sputtered in a 1:1 Ar/ O_2 sputter gas. Silicon substrate and air scattering have been subtracted from these patterns, such that diffraction from only the films

is shown. A broad (104) peak is observed for the as-deposited film, showing that this layer is composed of (104) out of plane textured nano-crystalline grains. The effect of heating this film to 300°C is illustrated in Fig. 6A, where the (104) peak becomes sharper and moves to the predicted equilibrium 2θ position, at 36.05°.

Figure 7 illustrates normalized (104) X-scan texture data. The (104) θ-2θ diffraction condition is satisfied while the out-of-plane orientation, X, is scanned. The intensity at any X is proportional to the number of LiCoO₂ unit cells that are oriented X degrees from the substrate surface normal.

Grain diameters are calculated using the Scherrer formula, and it was found that, as deposited, the grains are 4+/-0.5 nm in diameter, and the heating step increased the average grain diameter to 8+/-1 nm. Similar films grown to thicknesses up to 1.4 μm all have a strong (104) out of plane. It is interesting to note that if the substrate is kept static (i.e., is not in constant motion underneath the target) during growth, a strong (003) texture developed in some film areas.

The 1.1° peak shifts observed as a result of the heating step corresponds to a 2.6% change in the out-of-plane $d_{(104)}$ lattice parameter. The large value of this change makes it unlikely that this is a simple stress/strain effect. The lattice parameter change observed would require residual stresses orders of magnitude greater than those observed in thin films.

Figure 7 shows X scan texture plots of the (104) reflection of LiCoO_2 before and after the heating step. These data have been normalized to account for the dependence of diffraction volume with respect to X. The intensity of these normalized plots at any X is proportional to the number of unit cells that are in grains that have their (104) plane inclined X° from the substrate plane. The full width at half maximum (FWHM) of a Gaussian curve fit to the data is used as a means to quantify these results. It can be seen that the FWHM decreases from $15.4^\circ \pm 0.1^\circ$ to $14.3^\circ \pm 0.1^\circ$ as a result of the heating step. Though this change is statistically significant, it is not large and shows that, while the heating step doubles the average grain size, the degree of texture is not strongly increased.

The TEM images of 80 nm thick LiCoO_2 films sputtered onto holey carbon grids are shown in Figure 8, wherein it is shown that a TEM analysis of 100 nm thick LiCoO_2 films sputtered onto a holey carbon grid. Bright field images are shown for a film before and after heating. Significant grain growth as a result of the heating step may be observed.

The bright field images show that the microstructure is porous and contains well-defined grains that grow as a result of the heating step. As deposited, all the grains are similar in size, whereas after heating, some of the grains have grown to well over 10 nm in diameter whereas other grains show no change at all. The x-ray determination of grain size gives only an average value, so these TEM results are valuable in that

they show that heating the films to 300°C encourages some grains to more than triple their initial size while other grains display no increase at all.

5 Electrochemical cycling

Figure 9 shows the electrochemical performance of thin film batteries comprising as-deposited 200 nm thick LiCoO_2 cathodes. A voltage plateau is found to exist at approximately 2.8 V, while a discharge rate of even 50 μA severely limited the cell capacity, indicating that there is significant electronic resistance in these cells. The cycle life of these batteries is found to be limited to 200-300 cycles before losing 3/4 of original capacity. Fig. 9 also illustrates the cell discharge data from a thin film solid state battery created using a LiCoO_2 cathode deposited at room temperature with no heating step. Discharge currents range from 2 to 50 $\mu\text{A}/\text{cm}^2$.

Figure 10A shows a plot of cell potential vs. capacity for a LiCoO_2 thin film battery with a 0.190 μm thick cathode that was heated to 300°C for 1 hour. Figure 10A shows the cell discharge data from a thin film solid state battery created using a LiCoO_2 cathode after the 300°C heating step. Discharge currents range from 2 $\mu\text{A}/\text{cm}^2$ to 1 mA/cm^2 . Figure 10B shows the charge and discharge capacity versus cycle for a similar cell.

The capacity using a 2 $\mu\text{A}/\text{cm}^2$ discharge current is 66 $\mu\text{Ah}/\text{cm}^2\mu\text{m}$ (where the μm in these units refers to cathode thickness). The discharge voltage has a value of

approximately 3.9 V, however there is no perfectly flat voltage plateau.

Figure 10B contains a plot showing the cycle
5 life of a typical heat-treated LiCoO_2 cell. After an
initial loss of approximately 20% of the original
capacity over the first hundred cycles, the capacity
levels out at approximately $46 \mu\text{Ah}/\text{cm}^2\mu\text{m}$ and maintains at
this level for >2000 cycles. The average percent
10 capacity loss per cycle equilibrates at $-0.003\%/ \text{Cycle}$.

The results shown in Figures 6-8 illustrate that
polycrystalline LiCoO_2 films can be produced without any
substrate heating during or after growth. This result
15 contradicts four different previously published reports
that state RF sputtered LiCoO_2 is amorphous as deposited
at room temperature. There are two possible reasons for
this difference: [1] Previous studies did not use
synchrotron radiation and so were not able to detect
20 scattering from thin LiCoO_2 in the θ - 2θ geometry for films
this thin; or, [2] The combination of growth conditions
needed to create these textured nano-crystalline films are
not uncovered in other research efforts. It is well
known that films sputtered from targets of identical
25 composition can differ dramatically microstructurally
depending on the sputter system used, lending credence to
possibility [2] above.

The as-deposited films display a strong degree
30 of (104) out-of-plane texturing. It has been reported
elsewhere that, upon annealing, most LiCoO_2 films thinner
than $1\mu\text{m}$ have at least 10-20% of their grains oriented

with the (003) plane parallel to the substrate (thicker films are found to develop either (101) or (104)). In fact, an (003) out of plane texture is observed in certain areas in the films grown in the chamber used for our study if the substrate was held static during deposition. This difference is attributed to composition and environmental gradients inherent in the magnetron sputter environment.

Upon heating to 300°C for an hour, three trends are observed for the films: [1] the average grain size is found to roughly double. It is further established using TEM analysis that some grains grow to over 3 times their initial size, while others do not change at all. [2] The degree of texturing is found to increase only slightly: from an X-scan FWHM of 15.4° to 14.3°. [3] There is a large change in lattice parameter spacing, as the (104) d-spacing is found to decrease out of the plane of the film by approximately 3% while the in plane spacings expand by approximately 4%. The heating step therefore creates a film containing some significantly larger LiCoO₂ crystalline grains that were free of any significant lattice distortion. Electrochemically, it is likely that these qualities combine to create films that are more efficient conductors of both ions and electrons.

The analysis of the electrochemical performance of the batteries built in accordance with this invention indicates that the 300°C heating step significantly increases cell capacity and discharge voltage. The average discharge voltage rose to approximately 3.8 v from approximately 2.9 v and the rate capability is

enhanced such that increasing the discharge rate 3 orders of magnitude (from 2 μ A to 1 mA) results in a 50% loss in overall capacity for the depth of discharge used. This is a large improvement over the 75% capacity loss
5 observed when the discharge rate is raised to 50 μ A from 2 μ A in the batteries created without a heating step.

The cycle life for the cells created using heat-treated cathodes is found to exceed 6000 cycles.
10 During the first 100 cycles, the capacity decreases approximately 25% and is essentially constant for all subsequent cycles. This initial decrease in capacity was not observed in all cases, and the cause of this irreversible capacity loss is currently under
15 investigation.

The viability of creating high-capacity, high discharge rate thin-film batteries at processing temperatures that do not exceed 300°C has been shown. It
20 is established, in contrast to previous findings, that nano-crystalline highly (104) out-of-plane textured thin rhombohedral films of LiCoO₂ can be RF sputter deposited at room temperature and that the materials and electrochemical characteristics are enhanced for these
25 layers upon heating to 300°C. Materials analysis shows that the heating step enables a fraction of the grains to quadruple in size while fully relaxing any lattice strain. Though the rate capability of these cells is not as good as that of cells with 700°C annealed cathodes,
30 the new low-temperature cells are still able to sustain a 1 mA current load.

While the invention has been particularly shown
and described with reference to a preferred embodiment,
it will be understood by those skilled in the art that
various changes in form and detail may be made therein
5 without departing from the spirit and scope of the
invention.

Those skilled in the art will appreciate that
various adaptations and modifications of the just-described
10 preferred embodiments can be configured without departing
from the scope and spirit of the invention. Therefore, it
is to be understood that within the scope of the appended
claims, the invention may be practiced other than as
specifically described herein.

15